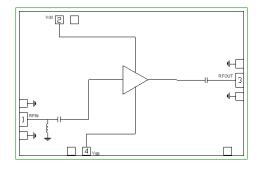


2-20 GHz Low Phase Noise Amplifier

Product Overview

The CMD274 is a wideband GaAs MMIC low phase noise amplifier die that is ideally suited for military, space and communications systems. At 10 GHz the device delivers 17 dB of gain, a saturated output power of +22 dBm and a noise figure of 3.2 dB. Also with an input signal of 10 GHz the amplifier provides low phase noise performance of -165 dBc/Hz at 10 kHz offset. The CMD274 is a 50 ohm matched design which eliminates the need for external DC blocks and RF port matching.

Functional Block Diagram



Key Features

- Ultra-Wideband Performance
- Low Phase Noise
- Low Current Consumption
- Small Die Size: 2300 um x 1500 um

Ordering Information

Part No.	Description
CMD274	2-20 GHz Low Phase Noise Amplifier,
CIVID214	50 Piece WP Sample

Electrical Performance ($V_{dd} = 5.0 \text{ V}$, $V_{gg} = 3.0 \text{ V}$, $T_A = 25 \text{ °C}$, F = 10 GHz)

Parameter	Min	Тур	Max	Units
Frequency Range		2 - 20		GHz
Gain		17		dB
Input Return Loss		12		dB
Output Return Loss		13		dB
Noise Figure		3.2		dB
Output P1dB		19		dBm
Saturated Output Power		22		dBm
Phase Noise @ 10 kHz Offset		-165		dBc/Hz
Supply Current		86		mA





Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, V _{dd}	7.5 V
Gate Voltage, V _{gg}	3.5 V
RF Input Power	+15 dBm
Channel Temperature, Tch	150 °C
Power Dissipation, Pdiss	720 mW
Thermal Resistance, θ _{JC}	90.3 °C/W
Operating Temperature	-55 to 85 °C
Storage Temperature	-55 to 150 °C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

Recommended Operating Conditions

Parameter	Min	Тур	Max	Units
V_{dd}	4.0	5.0	7.0	V
I _{dd}		86		mA
V _{gg}	2.0	3.0	3.3	V
I _{gg}		5		mA

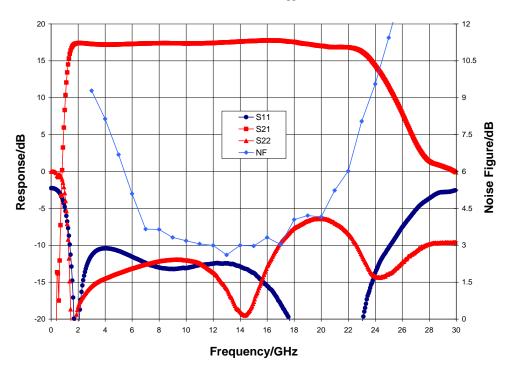
Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications ($V_{dd} = 5.0 \text{ V}$, $V_{gg} = 3.0 \text{ V}$, $T_A = 25 \text{ }^{\circ}\text{C}$)

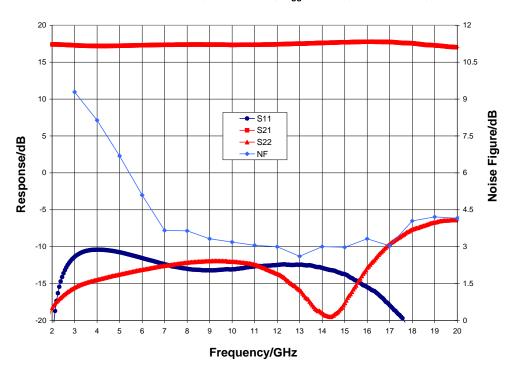
Parameter	Min	Тур	Max	Min	Тур	Max	Units
Frequency Range		2 - 10			10 - 20		GHz
Gain	14	17.5		14	17.5		dB
Noise Figure		6			3.5		dB
Input Return Loss		12			12		dB
Output Return Loss		13			12		dB
Output P1dB	16.5	19.5		13	17		dBm
Saturated Output Power		22			21		dBm
Output IP3		30.5			29.5		dBm
Phase Noise @ 10 kHz Offset		-165			-165		dBc/Hz
Supply Current	60	86	115	60	86	115	mA



Broadband Performance, V_{dd} = 5.0 V, V_{gg} = 3.0 V, I_{dd} = 74 mA, T_A = 25 °C

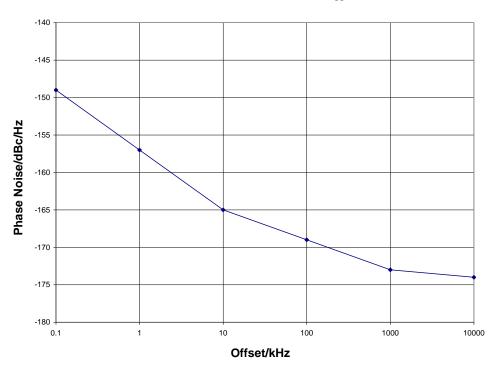


Narrow-band Performance, V_{dd} = 5.0 V, V_{gg} = 3.0 V, I_{dd} = 74 mA, T_A = 25 °C

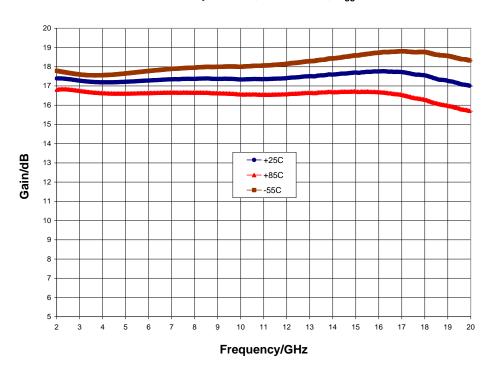




Additive Phase Noise @ Psat, V_{dd} = 5.0 V, V_{gg} = 3.0 V, T_A = 25 °C

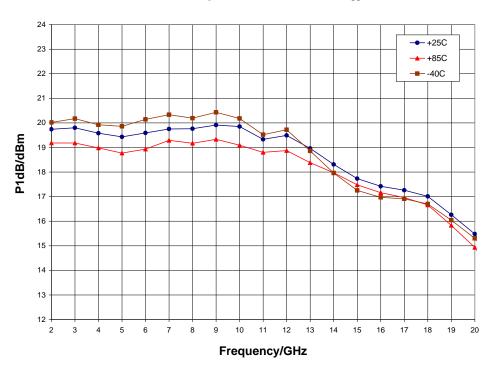


Gain vs. Temperature, V_{dd} = 5.0 V, V_{gg} = 3.0 V

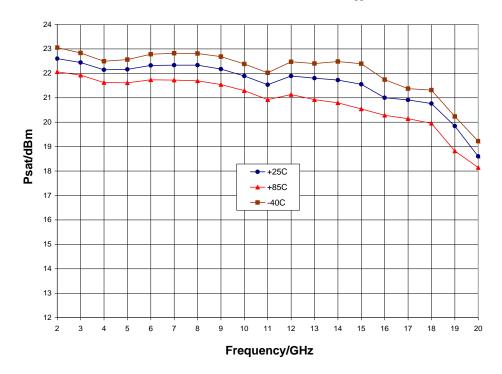






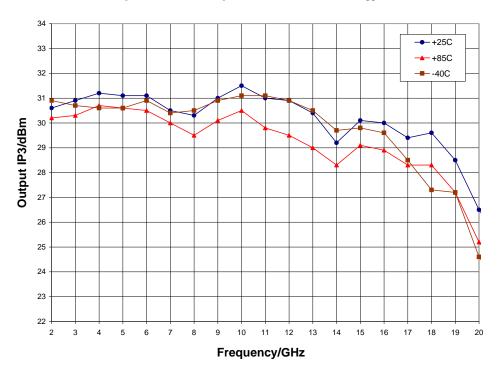


Psat vs. Temperature, V_{dd} = 5.0 V, V_{gg} = 3.0 V

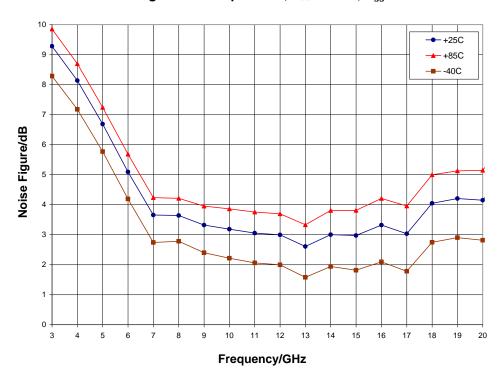








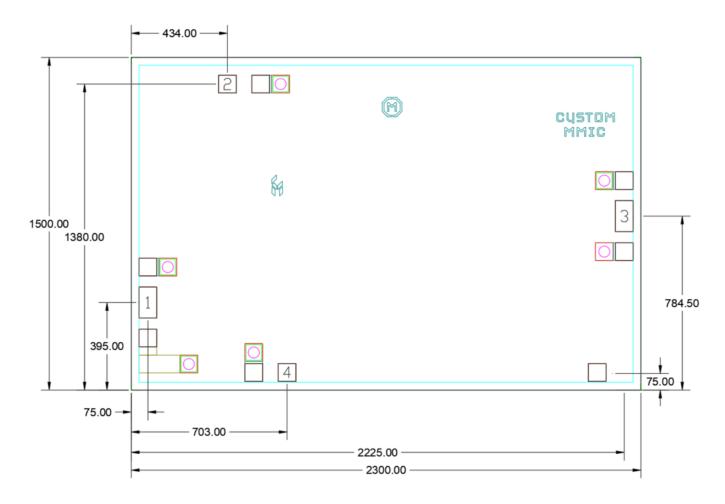
Noise Figure vs. Temperature, V_{dd} = 5.0 V, V_{gg} = 3.0 V





Mechanical Information

Die Outline (all dimensions in microns)



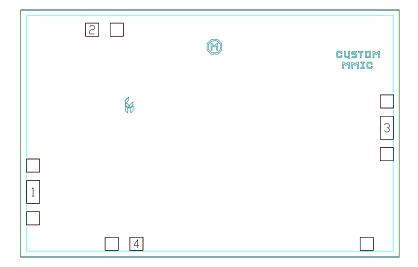
Notes:

- 1. No connection required for unlabeled pads
- 2. Backside is RF and DC ground
- 3. Backside and bond pad metal: Gold
- 4. Die is 100 microns thick
- 5. DC bond pads (2, 4) are 80 x 80 microns
- 6. RF bond pads (1, 3) are 80 x 140 microns



Pad Description

Pad Diagram



Functional Description

Pad	Function	Description	Schematic
1	RF in	DC coupled and 50 ohm matched	RF in O
2	V_{dd}	Power supply voltage Decoupling and bypass caps required	Vdd =
3	RF out	DC blocked and 50 ohm matched	
4	V _{gg}	Power supply voltage Decoupling and bypass caps required	O Vgg
Backside	Ground	Connect to RF / DC ground	GND =



Applications Information

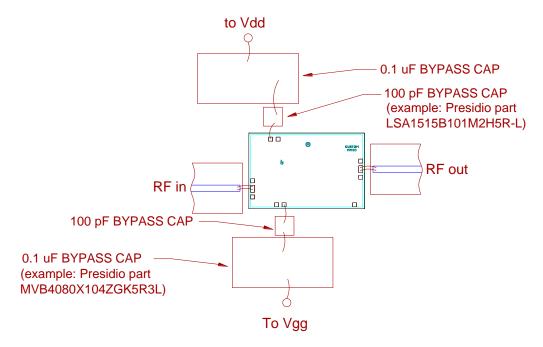
Assembly Guidelines

The backside of the CMD274 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines, and the RF decoupling capacitors placed in close proximity to the DC connections on chip.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require a double bond wire as shown.

The semiconductor is 100 um thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram

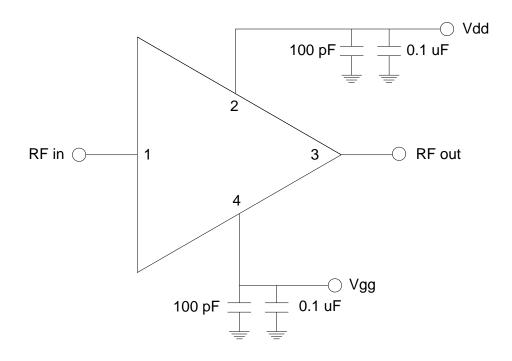


GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



Applications Information

Application Circuit



Biasing and Operation

The CMD274 is biased with a positive drain supply and positive gate supply. Performance is optimized when the drain voltage is set to +5.0 V. The recommended gate voltage is +3.0 V. The preferred biasing procedure is as follows:

Turn ON procedure:

- 1. Apply drain voltage V_{dd} and set to +5 V
- 2. Apply gate voltage V_{gg} and set to +3 V

Turn OFF procedure:

- 1. Turn off gate voltage Vgg
- 2. Turn off drain voltage V_{dd}

The preferred biasing procedure has been proven to be robust and should be used whenever possible. However, the CMD274 does allow for simultaneous biasing (applying V_{dd} and V_{gg} at the same time), and the use of a single voltage supply.

Refer to Application Note 103: Amplifier Biasing Techniques for instructions on how to implement a single supply biasing scheme.

For either approach, RF power can be applied at any time



Handling Precautions

Parameter	Rating	Standard	0 " 1
ESD – Human Body Model (HBM)	Class 1A	ESDA/JEDEC JS-001-2012	Caution! ESD-Sensitive Device

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- SVHC Free
- Halogen Free
- PFOS Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: <u>www.qorvo.com</u> Tel: 1-844-890-8163

Email: customer.support@gorvo.com

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